

(19) World Intellectual Property Organization
International Bureau



(43) International Publication Date
4 June 2009 (04.06.2009)

PCT

(10) International Publication Number
WO 2009/068884 A1

(51) International Patent Classification:

H01L 51/56 (2006.01) **H01L 21/38** (2006.01)
H01L 51/00 (2006.01)

(21) International Application Number:

PCT/GB2008/003965

(22) International Filing Date:

28 November 2008 (28.11.2008)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

60/990636 28 November 2007 (28.11.2007) US

(71) Applicant (for all designated States except US): **NATIONAL UNIVERSITY OF SINGAPORE** [SG/SG];
21 Lower Kent Ridge Road, Singapore 119077 (SG).

(72) Inventors; and

(75) Inventors/Applicants (for US only): **HO, Peter** [SG/SG];
National University of Singapore, Department of Physics,
21 Lower Kent Ridge Road, Singapore 119077 (SG).
CHIA, Perq-Jon [SG/SG]; National University of Singa-
pore, Department of Physics, 21 Lower Kent Ridge Road,
Singapore 119077 (SG). **CHUA, Lay-Lay** [SG/SG];
National University of Singapore, Department of Physics,
21 Lower Kent Ridge Road, Singapore 119077 (SG).

PING, Rui-Qi [SG/SG]; National University of Singa-
pore, Department of Physics, 21 Lower Kent Ridge Road,
Singapore 119077 (SG). **FRIEND, Richard, Henry**
[GB/GB]; 9 Station Road, Fulbourn, Cambridge CB21
5ER (GB).

(74) Agent: **RUSHTON, David, John**; Haseltine Lake, Red-
cliff Quay, 120 Redcliff Street, Bristol BS1 6HU (GB).

(81) Designated States (unless otherwise indicated, for every
kind of national protection available): AE, AG, AL, AM,
AO, AT, AU, AZ, BA, BB, BG, BH, BR, BW, BY, BZ, CA,
CH, CN, CO, CR, CU, CZ, DE, DK, DM, DO, DZ, EC, EE,
EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID,
IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK,
LR, LS, LT, LU, LY, MA, MD, ME, MG, MK, MN, MW,
MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT,
RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, ST, SV, SY, TJ,
TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM,
ZW.

(84) Designated States (unless otherwise indicated, for every
kind of regional protection available): ARIPO (BW, GH,
GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM,
ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM),
European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI,
FR, GB, GR, HR, HU, IE, IS, IT, LT, LU, LV, MC, MT, NL,
NO, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG,
CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:

— with international search report

(54) Title: MULTILAYER HETEROSTRUCTURES FOR APPLICATION IN OLEDs AND PHOTOVOLTAIC DEVICES

(57) Abstract: This invention relates to a supported polymer heterostructure and methods of manufacture. The heterostructure is suitable for use in a range of applications which require semiconductor devices, including photovoltaic devices and light-emitting diodes.

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